

**IF140, IF140A****N-Channel Silicon Junction Field-Effect Transistor**

- Low-Noise, High Gain Amplifiers**

**Absolute maximum ratings at  $T_A = 25^\circ\text{C}$** 

Reverse Gate Source & Reverse Gate Drain Voltage	- 20 V
Continuous Forward Gate Current	10 mA
Continuous Device Power Dissipation	375 mW
Power Derating	3 mW/ $^\circ\text{C}$
Storage Temperature Range	- 65 $^\circ\text{C}$ to 200 $^\circ\text{C}$

At 25 $^\circ\text{C}$  free air temperature:

		IF140		IF140A		Process NJ14AL	
		Min	Max	Min	Max	Unit	Test Conditions
Gate Source Breakdown Voltage	$V_{(\text{BR})\text{GSS}}$	- 20		- 20		V	$I_G = - 1 \mu\text{A}, V_{DS} = \emptyset\text{V}$
Gate Reverse Current	$I_{\text{GSS}}$		- 0.1		- 0.1	nA	$V_{GS} = - 15\text{V}, V_{DS} = \emptyset\text{V}$
			- 0.2		- 0.2	nA	$V_{GS} = - 15\text{V}, V_{DS} = \emptyset\text{V}$
Gate Source Cutoff Voltage	$V_{GS(\text{OFF})}$		- 6		- 6	V	$V_{DS} = 15\text{V}, I_D = 5 \text{nA}$
Gate Source Voltage	$V_{GS}$		- 5	- 2.5	- 6	V	$V_{DS} = 15\text{V}, I_D = 50 \mu\text{A}$
Gate Source Forward Voltage	$V_{GS(F)}$		1		1	V	$V_{DS} = \emptyset, I_G = 1 \text{mA}$
Drain Saturation Current (Pulsed)	$I_{\text{DSS}}$	5	15	5	15	mA	$V_{DS} = 15\text{V}, V_{GS} = \emptyset\text{V}$

**Dynamic Electrical Characteristics**

Common Source Forward Transmittance	$Y_{fs}$	4.5		4.5		mS	$V_{DS} = 15\text{V}, V_{GS} = \emptyset\text{V}$	$f = 1 \text{ kHz}$
Common Source Output Conductance	$Y_{os}$		0.05		0.05	$\mu\text{S}$	$V_{DS} = 15\text{V}, V_{GS} = \emptyset\text{V}$	$f = 1 \text{ kHz}$
Common Source Input Capacitance	$C_{iss}$		3		3	pF	$V_{DS} = 15\text{V}, V_{GS} = \emptyset\text{V}$	$f = 1 \text{ MHz}$
Common Source Reverse Transfer Capacitance	$C_{rss}$		0.6		0.6	pF	$V_{DS} = 15\text{V}, V_{GS} = \emptyset\text{V}$	$f = 1 \text{ MHz}$

		Typ	Typ				
Equivalent Short Circuit Input Noise Voltage	$\bar{e}_N$	4	4	nV/ $\sqrt{\text{Hz}}$	$V_{DS} = 12\text{V}, V_{GS} = \emptyset\text{V}$	$f = 10 \text{ Hz}$	

**TO-72 Package**

Dimensions in Inches (mm)

**Pin Configuration**

1 Source, 2 Drain, 3 Gate, 4 Case

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